NSN 5961-01-251-4033

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-251-4033 **Inclosure Material:** Metal **Overall Length:** Between 2.355 inches and 2.395 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 720.0 nonrepetitive peak reverse voltage and 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 100.00 amperes collector current, dc absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No